## Data Sheet

## FEATURES

Fixed gain of $\mathbf{2 0 ~ d B}$<br>Operational frequency of 1 MHz to 2.7 GHz<br>Linear output power up to $\mathbf{4 d B m}$<br>Input/output internally matched to $50 \Omega$<br>Temperature and power supply stable<br>Noise figure: $\mathbf{4 . 2 \mathrm { dB }}$<br>Power supply: 3 V or 5 V

## APPLICATIONS

## VCO buffers

General Tx/Rx amplification
Power amplifier predrivers
Low power antenna drivers

## GENERAL DESCRIPTION

The AD8354 is a broadband, fixed-gain, linear amplifier that operates at frequencies from 1 MHz up to 2.7 GHz . It is intended for use in a wide variety of wireless devices, including cellular, broadband, CATV, and LMDS/MMDS applications.

By taking advantage of ADI's high performance, complementary Si bipolar process, these gain blocks provide excellent stability over process, temperature, and power supply. This amplifier is single-ended and internally matched to $50 \Omega$ with a return loss of greater than 10 dB over the full operating frequency range.

The AD8354 provides linear output power of nearly 4.3 dBm with 20 dB of gain at 900 MHz when biased at 3 V and an external RF choke is connected between the power supply and the output pin. The dc supply current is 24 mA . At 900 MHz , the output third-order intercept (OIP3) is greater than 18 dBm ; at 2.7 GHz , the OIP3 is 14 dBm .

## FUNCTIONAL BLOCK DIAGRAM



Figure 1.

The noise figure is 4.2 dB at 900 MHz . The reverse isolation $\left(\mathrm{S}_{12}\right)$ is -33 dB at 900 MHz .

The AD8354 can also operate with a 5 V power supply; in which case, no external inductor is required. Under these conditions, the AD8354 delivers 4.88 dBm with 20 dB of gain at 900 MHz . The dc supply current is 26 mA . At 900 MHz , the OIP3 is greater than 19 dBm ; at 2.7 GHz , the OIP3 is 15 dBm . The noise figure is 4.4 dB at 900 MHz . The reverse isolation $\left(\mathrm{S}_{12}\right)$ is -33 dB .

The AD8354 is fabricated on ADI's proprietary, high performance, 25 GHz , Si complementary, bipolar IC process. The AD8354 is available in a chip scale package that uses an exposed paddle for excellent thermal impedance and low impedance electrical connection to ground. It operates over a $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ temperature range, and an evaluation board is also available.

Rev. F

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A. Tel: 781.329.4700 ©2002-2017 Analog Devices, Inc. All rights reserved. Technical Support

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## SPECIFICATIONS

$\mathrm{V}_{\mathrm{S}}=3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, 100 \mathrm{nH}$ external inductor between VOUT and VPOS, $\mathrm{Z}_{\mathrm{O}}=50 \Omega$, unless otherwise noted.
Table 1.

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OVERALL FUNCTION |  |  |  |  |  |
| Frequency Range |  | 1 |  | 2700 | MHz |
| Gain | $\mathrm{f}=900 \mathrm{MHz}$ |  | 19.5 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 18.6 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 17.1 |  | dB |
| Delta Gain | $\mathrm{f}=900 \mathrm{MHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -0.97 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -1.05 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -1.33 |  | dB |
| Gain Supply Sensitivity | VPOS $\pm 10 \%$, f $=900 \mathrm{MHz}$ |  | 0.54 |  | $\mathrm{dB} / \mathrm{V}$ |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 0.37 |  | $\mathrm{dB} / \mathrm{V}$ |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 0.2 |  | dB/V |
| Reverse Isolation ( $\mathrm{S}_{12}$ ) | $\mathrm{f}=900 \mathrm{MHz}$ |  | -33.5 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | -38 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | -32.9 |  | dB |
| RF INPUT INTERFACE Input Return Loss | Pin INPT |  |  |  |  |
|  | $\mathrm{f}=900 \mathrm{MHz}$ |  | 24.4 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 23 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 12.7 |  | dB |
| RF OUTPUT INTERFACE Output Compression Point | Pin VOUT |  |  |  |  |
|  | $\mathrm{f}=900 \mathrm{MHz}, 1 \mathrm{~dB}$ compression |  | 4.6 |  | dBm |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 3.7 |  | dBm |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 2.7 |  | dBm |
| Delta Compression Point | $\mathrm{f}=900 \mathrm{MHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 0.7 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 0.7 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 0.8 |  | dB |
| Output Return Loss | $\mathrm{f}=900 \mathrm{MHz}$ |  | 23.6 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 16.5 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 14.6 |  | dB |
| DISTORTION/NOISE |  |  |  |  |  |
| Output Third-Order Intercept | $\mathrm{f}=900 \mathrm{MHz}, \Delta \mathrm{f}=1 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-28 \mathrm{dBm}$ |  | 19 |  | dBm |
|  | $\mathrm{f}=1.9 \mathrm{GHz}, \Delta \mathrm{f}=1 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-28 \mathrm{dBm}$ |  | 16 |  | dBm |
|  | $\mathrm{f}=2.7 \mathrm{GHz}, \Delta \mathrm{f}=1 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-28 \mathrm{dBm}$ |  | 14.2 |  | dBm |
| Output Second-Order Intercept | $\mathrm{f}=900 \mathrm{MHz}, \Delta \mathrm{f}=1 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-28 \mathrm{dBm}$ |  | 29.7 |  | dBm |
| Noise Figure | $\mathrm{f}=900 \mathrm{MHz}$ |  | 4.2 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 4.8 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 5.4 |  | dB |
| POWER INTERFACE | Pin VPOS |  |  |  |  |
| Supply Voltage |  | 2.7 | 3 | 3.3 | V |
| Total Supply Current |  | 16 | 23 | 31 | mA |
| Supply Voltage Sensitivity |  |  | 6.2 |  | $\mathrm{mA} / \mathrm{V}$ |
| Temperature Sensitivity | $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 33 |  | $\mu \mathrm{A} /{ }^{\circ} \mathrm{C}$ |

$\mathrm{V}_{\mathrm{S}}=5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, no external inductor between VOUT and VPOS, $\mathrm{Z}_{\mathrm{O}}=50 \Omega$, unless otherwise noted.
Table 2.

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OVERALL FUNCTION |  |  |  |  |  |
| Frequency Range |  | 1 |  | 2700 | MHz |
| Gain | $\mathrm{f}=900 \mathrm{MHz}$ |  | 19.5 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 18.7 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 17.3 |  | dB |
| Delta Gain | $\mathrm{f}=900 \mathrm{MHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -0.93 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -0.99 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -1.21 |  | dB |
| Gain Supply Sensitivity | VPOS $\pm 10 \%, \mathrm{f}=900 \mathrm{MHz}$ |  | 0.32 |  | $\mathrm{dB} / \mathrm{V}$ |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 0.21 |  | $\mathrm{dB} / \mathrm{V}$ |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 0.08 |  | $\mathrm{dB} / \mathrm{V}$ |
| Reverse Isolation ( $\mathrm{S}_{12}$ ) | $\mathrm{f}=900 \mathrm{MHz}$ |  | -33.5 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | -37.6 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | -32.9 |  | dB |
| RF INPUT INTERFACE Input Return Loss | Pin INPT |  |  |  |  |
|  | $\mathrm{f}=900 \mathrm{MHz}$ |  | 24.4 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 23.9 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 13.5 |  | dB |
| RF OUTPUT INTERFACE Output Compression Point | Pin VOUT |  |  |  |  |
|  | $\mathrm{f}=900 \mathrm{MHz}$ |  | 4.8 |  | dBm |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 4.6 |  | dBm |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 3.6 |  | dBm |
| Delta Compression Point | $\mathrm{f}=900 \mathrm{MHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 0.37 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -0.14 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz},-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | -0.05 |  | dB |
| Output Return Loss | $\mathrm{f}=900 \mathrm{MHz}$ |  | 23.7 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 22.5 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  | 17.6 |  | dB |
| DISTORTION/NOISE |  |  |  |  |  |
| Output Third-Order Intercept | $\mathrm{f}=900 \mathrm{MHz}, \Delta \mathrm{f}=50 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-30 \mathrm{dBm}$ |  | 19.3 |  | dBm |
|  | $\mathrm{f}=1.9 \mathrm{GHz}, \Delta \mathrm{f}=50 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-30 \mathrm{dBm}$ |  | 17.3 |  | dBm |
|  | $\mathrm{f}=2.7 \mathrm{GHz}, \Delta \mathrm{f}=50 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-30 \mathrm{dBm}$ |  | 15.3 |  | dBm |
| Output Second-Order Intercept | $\mathrm{f}=900 \mathrm{MHz}, \Delta \mathrm{f}=1 \mathrm{MHz}, \mathrm{P}_{\text {IN }}=-28 \mathrm{dBm}$ |  | 28.7 |  | dBm |
| Noise Figure | $\mathrm{f}=900 \mathrm{MHz}$ |  | 4.4 |  | dB |
|  | $\mathrm{f}=1.9 \mathrm{GHz}$ |  | 5 |  | dB |
|  | $\mathrm{f}=2.7 \mathrm{GHz}$ |  |  |  |  |
| POWER INTERFACE | Pin VPOS |  |  |  |  |
| Supply Voltage |  | 4.5 | 5 | 5.5 | V |
| Total Supply Current | $\mathrm{T}_{\mathrm{A}}=27^{\circ} \mathrm{C}$ | 17 | 25 | 34 | mA |
| Supply Voltage Sensitivity |  |  | 4 |  | $\mathrm{mA} / \mathrm{V}$ |
| Temperature Sensitivity | $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq+85^{\circ} \mathrm{C}$ |  | 28 |  | $\mu \mathrm{A} /{ }^{\circ} \mathrm{C}$ |

ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
| :--- | :--- |
| Supply Voltage, VPOS | 5.5 V |
| Input Power (re: $50 \Omega$ ) | 10 dBm |
| $\quad$ Equivalent Voltage | 700 mV rms |
| Internal Power Dissipation |  |
| $\quad$ Paddle Not Soldered | 325 mW |
| $\quad$ Paddle Soldered | 812 mW |
| $\theta_{\mathrm{JA}}$ (Paddle Soldered) | $80^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\mathrm{JA}}$ (Paddle Not Soldered) | $200^{\circ} \mathrm{C} / \mathrm{W}$ |
| Maximum Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Lead Temperature (Soldering, 60 sec) |  |
| $\quad$ AD8354ACP (Non-RoHS Compliant) | $240^{\circ} \mathrm{C}$ |
| AD8354ACPZ (RoHS Compliant) | $260^{\circ} \mathrm{C}$ |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. <br> Charged devices and circuit boards can discharge <br> without detection. Although this product features <br> patented or proprietary protection circuitry, damage <br> may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to <br> avoid performance degradation or loss of functionality. |
| :--- | :--- |

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



Table 4. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1,8 | COM1 | Device Common. Connect to low impedance ground. |
| 2 | NC | No Connection. |
| 3 | INPT | RF Input Connection. Must be ac-coupled. |
| 4,5 | COM2 | Device Common. Connect to low impedance ground. |
| 6 | VPOS | Positive Supply Voltage. |
| 7 | VOUT | RF Output Connection. Must be ac-coupled. |

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 3. $S_{11}$ vs. Frequency, $V_{S}=3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, 100 \mathrm{MHz} \leq f \leq 3 \mathrm{GHz}$


Figure 4. Gain vs. Frequency, $V_{S}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and $3.3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 5. Reverse Isolation vs. Frequency, $V_{S}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and $3.3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 6. S22 vs. Frequency, $V_{s}=3 V, T_{A}=25^{\circ} \mathrm{C}, 100 \mathrm{MHz} \leq f \leq 3 \mathrm{GHz}$


Figure 7. Gain vs. Frequency, $V_{s}=3 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 8. Reverse Isolation vs. Frequency, $V_{S}=3 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 9. $P_{1 d B}$ vs. Frequency, $V_{s}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and $3.3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 10. Distribution of $P_{1 d B}, V_{S}=3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 11. OIP3 vs. Frequency, $V_{S}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and $3.3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 12. $P_{1 d B}$ Vs. Frequency, $V_{s}=3 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 13. Distribution of OIP3, $V_{S}=3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 14. OIP3 vs. Frequency, $V_{s}=3 V_{,} T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 15. Noise Figure vs. Frequency, $V_{s}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and $3.3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 16. Distribution of Noise Figure, $V_{s}=3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 17. $S_{11}$ vs. Frequency, $V_{S}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, 100 \mathrm{MHz} \leq f \leq 3 \mathrm{GHz}$


Figure 18. Noise Figure vs. Frequency, $V_{s}=3 V, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 19. Supply Current vs. Temperature, $V_{S}=2.7 \mathrm{~V}, 3 \mathrm{~V}$, and 3.3 V


Figure 20. $S_{22}$ vs. Frequency, $V_{S}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, 100 \mathrm{MHz} \leq f \leq 3 \mathrm{GHz}$


Figure 21. Gain vs. Frequency, $V_{S}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and $5.5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 22. Reverse Isolation vs. Frequency, $V_{s}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and $5.5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 23. $P_{1 d B} V s$. Frequency, $V_{s}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and $5.5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 24. Gain vs. Frequency, $V_{s}=5 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 25. Reverse Isolation vs. Frequency, $V_{S}=5 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 26. $P_{1 d B}$ vs. Frequency, $V_{S}=5 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 27. Distribution of $P_{1 d B}, V_{S}=5 V, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 28. OIP3 vs. Frequency, $V_{s}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and $5.5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 29. Noise Figure vs. Frequency, $V_{S}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and $5.5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}$


Figure 30. Distribution of OIP3, $V_{S}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 31. OIP3 vs. Frequency, $V_{S}=5 \mathrm{~V}, T_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 32. Noise Figure vs. Frequency, $V_{S}=5 \mathrm{~V}, \mathrm{~T}_{A}=-40^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, and $+85^{\circ} \mathrm{C}$


Figure 33. Distribution of Noise Figure, $V_{S}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=2.2 \mathrm{GHz}$


Figure 34. Supply Current vs. Temperature, $V_{S}=4.5 \mathrm{~V}, 5 \mathrm{~V}$, and 5.5 V


Figure 35. Supply Current vs. Pout and Temperature, $V_{s}=5 \mathrm{~V}$


Figure 36. Output Power and Gain vs. Input Power, $V_{S}=3 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=900 \mathrm{MHz}$


Figure 37. Output Power and Gain vs. Input Power, $V_{S}=5 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}, f=900 \mathrm{MHz}$

## THEORY OF OPERATION

The AD8354 is a 2-stage, feedback amplifier employing both shunt-series and shunt-shunt feedback. The first stage is degenerated and resistively loaded and provides approximately 10 dB of gain. The second stage is a PNP-NPN Darlington output stage, which provides another 10 dB of gain. Seriesshunt feedback from the emitter of the output transistor sets the input impedance to $50 \Omega$ over a broad frequency range. Shuntshunt feedback from the amplifier output to the input of the Darlington stage helps to set the output impedance to $50 \Omega$. The amplifier can be operated from a 3 V supply by adding a choke inductor from the amplifier output to VPOS. Without this choke inductor, operation from a 5 V supply is also possible.

## BASIC CONNECTIONS

The AD8354 RF gain block is a fixed gain amplifier with singleended input and output ports whose impedances are nominally equal to $50 \Omega$ over the frequency range 1 MHz to 2.7 GHz . Consequently, it can be directly inserted into a $50 \Omega$ system with no impedance matching circuitry required. The input and output impedances are sufficiently stable vs. variations in temperature and supply voltage that no impedance matching compensation is required. A complete set of scattering parameters is available at www.analog.com.

The input pin (INPT) is connected directly to the base of the first amplifier stage, which is internally biased to approximately 1 V ; therefore, a dc blocking capacitor should be connected between the source that drives the AD8354 and the input pin, INPT.

It is critical to supply very low inductance ground connections to the ground pins (Pin 1, Pin 4, Pin 5, and Pin 8) as well as to the backside exposed paddle. This ensures stable operation.

The AD8354 is designed to operate over a wide supply voltage range, from 2.7 V to 5.5 V . The output of the part, VOUT, is taken directly from the collector of the output amplifier stage. This node is internally biased to approximately 3.2 V when the supply voltage is 5 V . Consequently, a dc blocking capacitor should be connected between the output pin, VOUT, and the load that it drives. The value of this capacitor is not critical, but it should be 100 pF or larger.

When the supply voltage is 3 V , it is recommended that an external RF choke be connected between the supply voltage and the output pin, VOUT. This increases the dc voltage applied to the collector of the output amplifier stage, which improves performance of the AD8354 to be very similar to the performance produced when 5 V is used for the supply voltage. The inductance of the RF choke should be approximately 100 nH , and care should be taken to ensure that the lowest series self-resonant frequency of this choke is well above the maximum frequency of operation for the AD8354.

Bypass the supply voltage input, VPOS, using a large value capacitance (approximately $0.47 \mu \mathrm{~F}$ or larger) and a smaller, high frequency bypass capacitor (approximately 100 pF ) physically located close to the VPOS pin.

The recommended connections and components are shown in Figure 41.

## APPLICATIONS INFORMATION

The AD8354 RF gain block can be used as a general-purpose, fixed gain amplifier in a wide variety of applications, such as a driver for a transmitter power amplifier (see Figure 38). Its excellent reverse isolation also makes this amplifier suitable for use as a local oscillator buffer amplifier that would drive the local oscillator port of an upconverter or downconverter mixer (see Figure 39).


Figure 38. AD8354 as a Driver Amplifier


Figure 39. AD8354 as a LO Driver Amplifier

## LOW FREQUENCY APPLICATIONS BELOW $100 \mathbf{~ M H z}$

The AD8354 RF gain block can be used below 100 MHz . To accomplish this, the series dc blocking capacitors, C 1 and C 2 , need to be changed to a higher value that is appropriate for the desired frequency. C 1 and C 2 were changed to $0.1 \mu \mathrm{~F}$ to accomplish the sweeps in Figure 40.


Figure 40. Low Frequency Application from 300 kHz to 100 MHz at 5 V VPOS, -12 dBm Input Power

## EVALUATION BOARD

Figure 41 shows the schematic of the AD8354 evaluation board. Note that L1 is shown as an optional component that is used to obtain maximum gain only when $\mathrm{V}_{\mathrm{P}}=3 \mathrm{~V}$. The board is powered by a single supply in the 2.7 V to 5.5 V range. The power supply is decoupled by a $0.47 \mu \mathrm{~F}$ and a 100 pF capacitor.


Figure 41. Evaluation Board Schematic

Table 5. Evaluation Board Configuration Options

| Component | Function | Default <br> Value |
| :--- | :--- | :--- |
| C1, C2 | AC coupling capacitors. | 1000 pF, |
| C3 |  | 0603 |
| C4 | High frequency bypass capacitor. | 100 pF, |
| L1 | Low frequency bypass capacitor. | 0603 |
|  |  | $0.47 \mu \mathrm{~F}$, |
| 0603 |  |  |
|  | Optional RF choke, used to increase <br> current through output stage when | 100 nH, |
|  | 0603 |  |
|  | $\mathrm{~V}_{\mathrm{P}}=3 \mathrm{~V}$. Not recommended for use |  |
| when $\mathrm{V}_{\mathrm{P}}=5 \mathrm{~V}$. |  |  |



Figure 42. Silkscreen Top


Figure 43. Component Side

## OUTLINE DIMENSIONS



ORDERING GUIDE

| Model $^{1}$ | Temperature Range | Package Description | Package Option | Branding |
| :--- | :--- | :--- | :--- | :--- |
| AD8354ACPZ-REEL7 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $8-L e a d ~ L F C S P, ~ 7 " ~ T a p e ~ a n d ~ R e e l ~$ <br> Evaluation Board | CP-8-23 | 0 C |

${ }^{1} Z=$ RoHS Compliant Part.

